

# MASTR Personal Series PROGRESS LINE

PE MODELS
SYSTEMS BOARD AND CASE ASSEMBLY 19D413548G1



### **SPECIFICATIONS** \*

MODEL NUMBERS

19D413548G1

CONTROLS:

138 - 174 MHz

Volume ON-OFF Switch

Squelch Control

Two-Frequency Selector Switch PTT Switch Tone Option Switch

Flexible Antenna

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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— WARNING —

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external appartus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

#### ADDEMDUM #1 TO LBI4666, LBI4662, LBI4612 and LBI4693

This addendum adds to LBI4666, LBI4662, LBI4612 and LBI4693 the revision changing PTT switch board A719. It includes the revision letter change, the Outline Diagram, Schematic Diagram and the Parts List for the new PTT switch board.

#### REVISION LETTER

REV. G - System Board and Case Assembly 19D413548G14 REV. G - System Board and Case Assembly 19D413548G15 REV. H - System Board and Case Assembly 19D413548G16 REV. G - System Board and Case Assembly 19D413548G17 REV. J - System Board and Case Assembly 19D413548G18 REV. A - System Board and Case Assembly 19D413548G21 REV. A - System Board and Case Assembly 19D413548G22

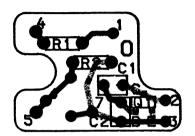
To incorporate a new design PTT switch board. Changed A719 from 19B232586G2 to 19B233821G1.

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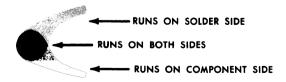
# OUTLINE DIAGRAM



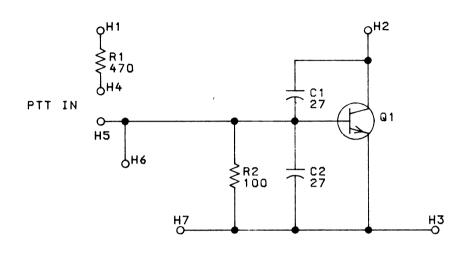
# LEAD IDENTIFICATION FOR Q1



(19B233822, Rev. 0) (19A143811, Sh. 1, Rev. 0) (19A143811, Sh. 2, Rev. 0)



# SCHEMATIC DIAGRAM



ALL RESISTORS ARE 1/8 WATT UNLESS
OTHERWISE SPECIFIED AND RESISTOR
VALUES IN OHMS UNLESS FOLLOWED BY
K-1000 OHMS OR MEG-1,000,000 OHMS.
CAPACITOR VALUES IN PICOFARADS (EQUAL
TO MICROMICROFARADS) UNLESS FOLLOWED
BY UF-MICROFARADS.INDUCTANCE VALUES
IN MICROHENRYS UNLESS FOLLOWED BY
MH-MILLIHENRYS OR H-HENRYS.

(19B233837, Rev. 1)

SYMBOL	GE PART NO	DESCRIPTION
A719		PUSH TO TALK SWITCH BOARD 19123382101
C1 and C2	19A700222P44	Ceramic: 27pf ±5%, 100VDCW; temp coef -80PPM.
Q1	19A134739P1	Silicon, NPN.
R1	3R151P471J	Composition: 470 ohms $\pm 5\%$ , $1/8$ W. Composition: 100 ohms $\pm 5\%$ , $1/8$ W.
R2	3R151P101J	

#### DESCRIPTION

System Board A701 provides system interconnections for the transmitter, receiver, tone options and operating controls. In addition to the transmitter modules, the system board contains the system relay and the audio and DC switching circuitry.

Jacks J702 and J703 are connected to the system board and provide contacts for an external antenna, speaker, and microphone.

J702 provides contacts for the external antenna and speaker, and J703 provides contacts for an external microphone. Placing the radio into the vehicular charger automatically connects the jack contacts to the external circuitry. The radio is also connected to the external antenna when placed in the desk charger.

#### CIRCUIT ANALYSIS

#### AUDIO SWITCHING

Audio switching for local speaker/microphone LS1 is controlled by diode CR5 as shown in Figure 1.

Pressing PTT switch S701 forward biases diode CR5, permitting audio from LS2 to be applied to transmitter audio module A1.

Keying the external microphone directly applies audio to the audio module.

#### DC SWITCHING

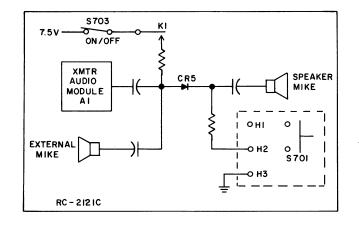
Operation of system relay K1 is controlled by diode CR2 (see Figure 2).

Pressing S701 forward biases CR2, completing the relay path to ground. This energizes relay K1, and switches the battery voltage to the transmitter audio and regulator modules. Energizing K1 also connects the transmitter output to the antenna.

Keying the external microphone directly energizes relay Kl.

#### PTT SWITCH

Solid state PTT switch S701 forward biases diode CR2 to energize relay K1 and key the radio. When S701 is pressed PNP transistor Q1 conducts. Transistor Q1 conducting applies a positive voltage to the base of NPN transistor Q2, causing Q2 to also conduct. Transistor Q2 conducting, provides a conduction path to ground for diode CR2. Relay K1 is energized and the radio is keyed.



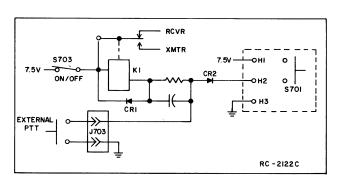


Figure 1 - Audio Switching Circuit

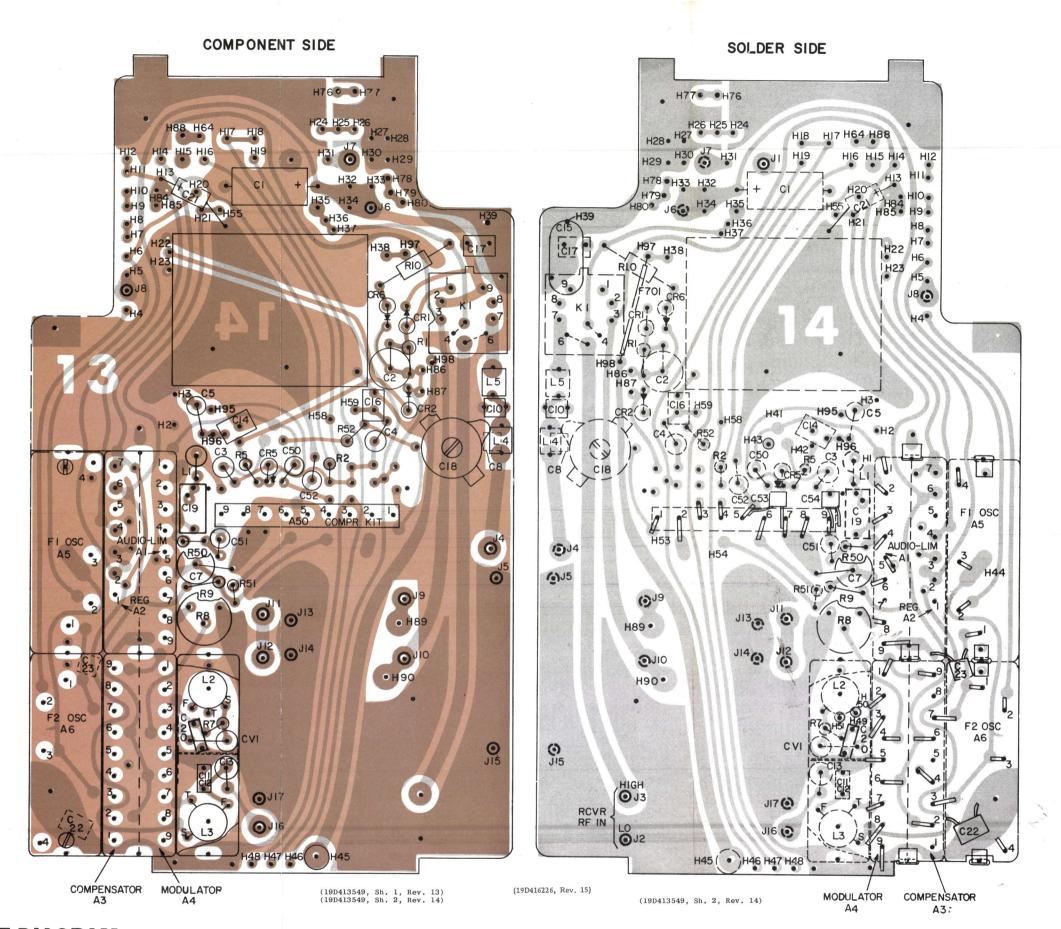
Figure 2 - DC Switching Circuit

GENERAL ELECTRIC COMPANY• MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS•LYNCHBURG, VIRGINIA 24502 U.S.A.

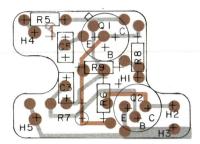


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A719



LEAD IDENTIFICATION FOR QI AND Q2



IN-LINE TRIANGULAR
TOP VIEW

NOTE, LEAD ARRANGEMENT, AND NOT
CASE SHAPE, IS DETERMINING
FACTOR FOR LEAD IDENTIFICATION

(19B233296, Rev. 3) (19B232970, Sh. 1, Rev. 1) (19B232970, Sh. 2, Rev. 2)

RUNS ON SOLDER SIDE

RUNS ON BOTH SIDES

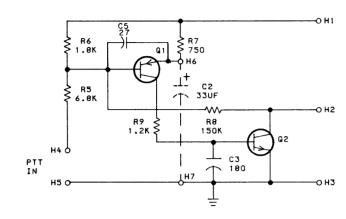
RUNS ON COMPONENT SIDE

# **OUTLINE DIAGRAM**

138—174 MHz SYSTEM BOARD

LBI4666

# A719



NOTE: C2 IS PART OF KIT 19A136579

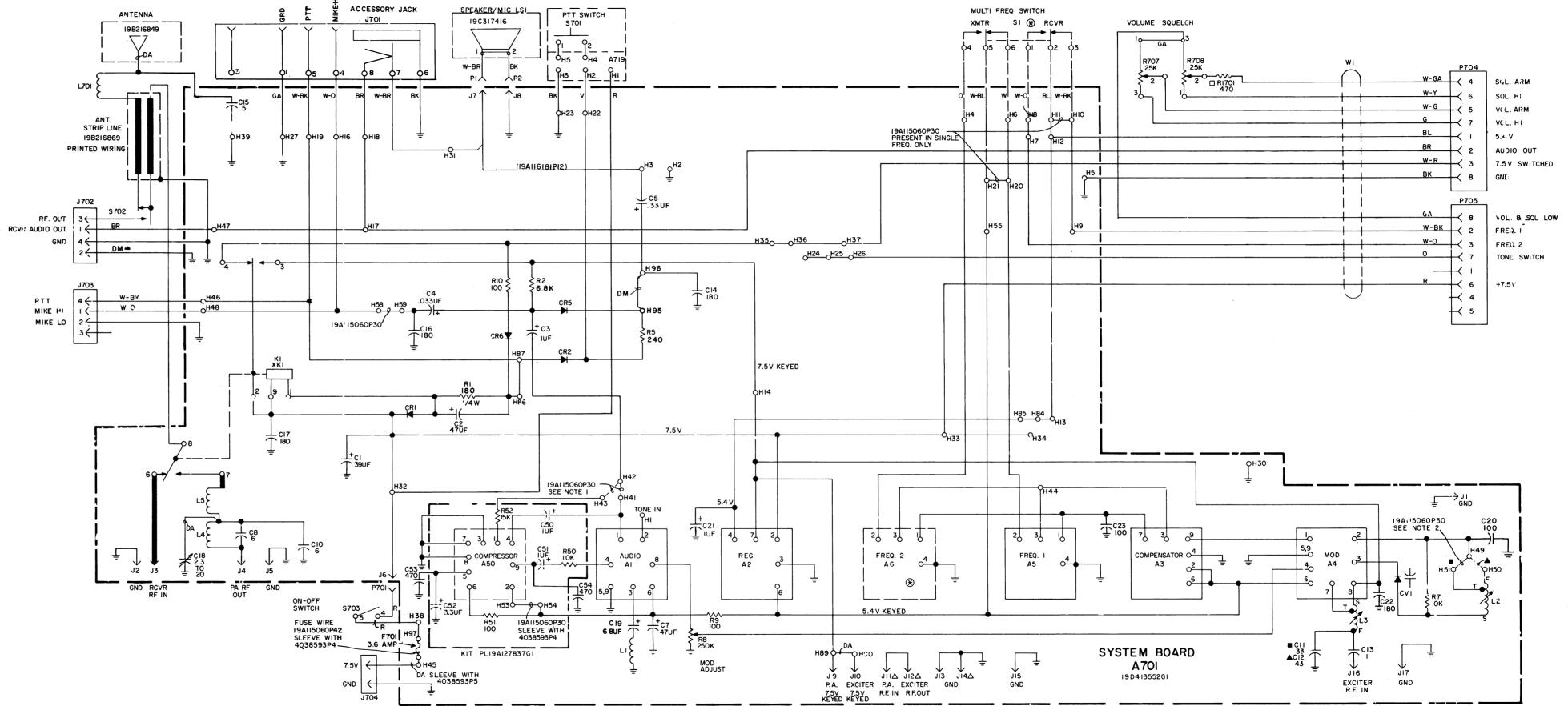
REV LETTER

MODEL NO

PL19B23258662

ALL RESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K-1000 OHMS. CAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF-MICROFARADS. INDUCTANCE VALUES
IN MICROHENRYS UNLESS FOLLOWED BY
MH-MILLIHENRYS OR H-HENRYS.

(19B232959, Rev. 4)



(19R621340, Rev. 30)

SEE APPLICABLE PRODUCTION CHANGE SHEETS IN INSTRUCTION BOOK SECTION: DEALING WITH THIS UNIT, FOR DESCRIPTION OF CHANGES UNDER EACH REVISION LETTER.

THIS ELEM DIAG APPLIES TO REV LETTER MODEL NO PL 19D413548G1 PL19D413552GI PL19A127837G1

ALL RESISTORS ARE 1/8 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG=1,000,000 OHMS OR MEG=1,000,000 OHMS OR MEG=1,000,000 OHMS OR MEGENIAL OF MICROMICROFARADS) UNLESS FOLLOWED BY UF= MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H=HENRYS.

IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

- I CONNECT HOLE 42 TO HOLE 41 WHEN COMPRESSOR A707 IS NOT USED. CONNECT HOLE 42 TO HOLE 43 WHEN COMPRESSOR A707 IS USED.
- 2. AUSED IN LO SPLIT (132-150.8 MHZ)

  JUSED IN HI SPLIT (150.8-174MHZ)

  PRESENT IN HI POWER UNITS

  ANOT PRESENT IN HI POWER UNITS 3. DA= #22 AWG
- THESE ITEMS ARE PART OF KIT PLIPAIR7828.
- ☐ RI701 IS PART OF KIT PLI9AI30602GI 4. GND MAY BE MADE THROUGH CAN ONLY,ON SICOMS.

# **SCHEMATIC DIAGRAM**

138—174 MHz SYSTEM BOARD

Issue 7

LBI4666

PARTS LIST

LB14234K

SYSTEM BOARD/CASE ASSEMBLY 19D413548G1 AND ASSOCIATED ASSEMBLIES GE PART NO. DESCRIPTION 19C320062G1 Transmitter Audio Module. (Used on boards of REV A and later). Transmitter Audio Module. (Used on boards of REV 0 only). 19C317167G4 Regulator Module. A2\* 19C328070G1 In REV H & earlier Oscillator Compensator Module. (Used on boards of REV A and later).  $\,$ 19C320060G1 Oscillator Compensator Module. (Used on boards of REV 0 only). Modulator Module. (Used on boards of REV A 19C320084G1 19C317388G1 Modulator Module. (Used on boards of REV 0 only). - - - - - - - - CAPACITORS - - - - - - -Tantalum: \*39  $\mu$ f  $\pm 20\%$ , 10 VDCW; sim to Sprague Type 162D. 5491674P30 Tantalum: 47  $\mu\text{f}$  ±20%, 6 VDCW; sim to Sprague Type 162D. 5491674P42 Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D. 5491674Pl Tantalum: 0.033  $\mu f$   $\pm 10\%$  , 35 VDCW; sim to Kemet T376P33K03AS. 5491674P51 Tantalum: 0.068 µf ±10%, 20 VDCW; sim to Sprague Type 162D. 5491674P49 Tantalum: 1.0  $\mu$ f +40-20%, 10 VDCW; sim to Sprague Type 162D. 5491674P1 Tantalum: 0.033  $\mu\text{f}$   $\pm10\%$  , 35 VDCW; sim to Kemet T376P33K03AS. 5491674P51 Tantalum: 1.0  $\mu$ f +40-20%, 10 VDCW; sim to Sprague Type 162D. 5491674P1 Tantalum: 0.33 µf ±10%, 20 VDCW; sim to Sprague Kemet T376B334K02OAS. 5491674P52 Tantalum: 0.68  $\pm 10\%$ , 10 VDCW; sim to Sprague Type 162D. 5491674P48 In REV B-F: Ceramic: 0.022 µf ±20%, 50 VDCW. 19A116244P2 In 19D413552Gl of REV A & earlier: Tantalum: 1.0  $\mu$ f +40-20%, 10 VDCW; sim to Sprague Type 162D. 5491674P1 Tantalum: 47  $\mu f$   $\pm 20\%$ , 4 VDCW; sim to Sprague Type 162D. Deleted by REV A. 5491674P26 Tantalum: 47  $\mu$ f  $\pm 20\%$ , 6 VDCW; sim to Sprague Type 162D. 5491674P42 Ceramic: 6 pf ±5%, 100 VDCW; temp coef 0 PPM. 19A116114P20 Ceramic: 6 pf ±5%, 100 VDCW; temp coef 0 PPM. 19A116114P20 Phenolic: 1.0 pf  $\pm 5\%$ , 500 VDCW. 19A700013P13

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
C14	19A116114P10073	Ceramic: 180 pf ±5%, 100 VDCW; temp coef -3300			MICROPHONES		
C15	5496218P36	PPM.  Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	MK1*	19B201559P1	Cartridge, controlled magnetic: 2K ohms imp; sim to Shure Bros. MC30. Deleted in 19D413552Gl by	Q1	19A129187P1
C16 and C17	19A116114P10073	Ceramic: 180 pf ±5%, 100 VDCW; temp coef -3300 PPM.			REV B.	Q2	19A116201P3
C18	19A7000012P2	Variable: 2.5 to 20 pf, 200 VDCW; -250 -700 temp coef Parts/M/°C; sim to Panasonic ECV-12W20X32.	Rl*	19A700106P45	Composition: 180 ohms ±5%, 1/4 w. In REV E:	R1 R2	3R151P103J 3R151P332J
C19*	19C307102P19	Tantalum: 68 µf ±20%, 4 VDCW. Added by REV A.		3R152P221J	Composition: 220 ohms ±5%, 1/4 w.	R2 R3	3R151P332J 3R151P154J
C20*	19A116114P8065	Ceramic: 100 pf ±5%, 100 VDCW; temp coef -1500 PPM. Added by REV A.			In REV D & earlier:	R4	3R151P182J
C21*	5491674P1	Tantalum: 1.0 µf +40-20%, 10 VDCW; sim to Sprague Type 162D. Added by REV J.		3R151P391J	Composition: 390 ohms ±5%, 1/8 w.	R5	3R151P682J
C22*	19A116114P10073	Ceramic: 180 pf ±5%, 100 VDCW; temp coef -3300	R2*	3R151P683J	Composition: 68K ohms ±5%, 1/8 w  In REV F & earlier:	R6 R7	3R151P182J 3R151P102J
<b>500</b> t	19A116114P10065	PPM. Added by REV L.		3R151P913J	Composition: 91K ohms ±5%, 1/8 w.	R8	3R151P154J
C23*	194116114910065	Ceramic: 100 pf ±5%, 100 VDCW; temp coef -3300 PPM. Added by REV L.	R3*	3R151P103J	Composition: 10K ohms ±5%, 1/8 w. Deleted by REV D.	R9	3R151P122J
		DIODES AND RECTIFIERS	R5*	3R151P241J	Composition: 240 ohms ±5%, 1/8 w.		
CR1*	19A115100P1	Silicon: sim to Type lN458A.			In REV F & earlier:	J701	19B216594G2
		In REV C & earlier:		3R151P103J	Composition: 10K ohms ±5%, 1/8 w.	J702	
	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	R6*	3R151P222J	Composition: 2.2K ohms $\pm 5\%$ , 1/8 w. Deleted by REV G.	J703	
CR2*	19A115100P1	Silicon: sim to Type lN458A.	R7	3R151P103J	Composition: 10K ohms ±5%, 1/8 w.	J704	
	5494922P1	In REV C & earlier: Silicon; sim to Hughes 1N456.	R8	19A116412P4	Variable, cermet: 250K ohms ±10%, 1/2 w;		
CR3*	5494922P1 5494922P1	Silicon; sim to Hughes 1N456. Deleted by REV D.			sim to Helipot Model 62 PF.	K2.*	19A127836G1
and CR4*	010102211		R9 and R10	3R151P101K	Composition: 100 ohms ±10%, 1/8 w.		
CR5*	19A115100Pl	Silicon: sim to Type lN458A.					_
		In REV C & earlier:	XK1*	19A115834P5	Contact, electrical: sim to AMP 3-331272-5.	L701	19A127815P1
	5494922P1	Silicon; sim to Hughes 1N456.			(Quantity 7). Deleted by REV E.		
CR6	19A115250P1 5495769P9	Silicon, fast recovery, 225 mA, 50 PIV. Diode, silicon.	A719*		PUSH TO TALK SWITCH BOARD 198232586G2 (Added by REV J)	P701	19A115834P4
						P704 and P705	19A127569P1
			C1*	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300	P 703	
F701*	19A127884G1	Fuse Kit. Added by REV K.			PPM. Deleted by REV A.	R707	19A116227P1
_		JACKS AND RECEPTACLES	C3	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.		
J1* thru J5*	19A116366P4	Contact, electrical: sim to Concord 10-891-1.	C5*	19A116114P2044	Ceramic: 27 pf $\pm 5\%$ , 100 VDCW; temp coef -80 PPM. Added by REV B.	R708	19A116227P2
	19A116366P1	In REV D & earlier:  Contact, electrical: sim to Cambion 460-3232-					
	15/11/05/07/1	01-03.	Q1	19A129187P1	Silicon, PNP.	8701	
J6 thru J8	19A116366P2	Contact, electrical: sim to Cambion 460-3233- 01-03.	Q2	19A116201P3	Silicon, NPN.	S702	
J9*	19A116366P4	Contact, electrical: sim to Concord 10-891-1.			RESISTORS	S703	
thru J17*		In REV D & earlier:	R5	3R151P682J	Composition: 6.8K ohms ±5%, 1/8 w.	1	
	19A116366P1	Contact, electrical; sim to Cambion 460-3232-01-03.	R6	3R151P182J	Composition: 1.8K ohms ±5%, 1/8 w.	W1	19C330826G1
	10.111.00001.1		R7*	3R151P751J	Composition: 750 ohms ±5%, 1/8 w.	<b>!</b>	
		RELAYS			Earlier than REV A:	1	
K1*	19B209562P2	Hermetic sealed: between 45-100 ohms , 2 form C contacts, 5.0 VDC nominal, 1.0 w max operating;	R8	3R151P102J 3R151P154J	Composition; 1K ohms ±5%, 1/8 w.  Composition: 250K ohms ±5%, 1/8 w.		
		sim to GE 3SCS1002A2. In REV E:	R9	3R151P122J	Composition: 1.2K ohms ±5%, 1/8 w.		
	19B209562P1	Hermetic sealed: 98 ohms ±10%, 2 form C contacts,			THE THE TALK OF THE POARD		
		6.0 VDC nominal, 1.0 w max operating; sim to GE 3SCS1001A2.	A719*		PUSH TO TALK SWITCH BOARD 19B232586G1 (Added by REV H) (Deleted by REV J)	181*	19A134949P1
Ll	19B209420P114						
		sim to Jeffers 4436-1K.	C1	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM.		19A116090P1
L2	19A127798G1	Coil: 6.05-6.50 μh.	сз	19A116114P10073	PPM.  Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300		
L3	19B216910G1 19B216320P3	Coil.	"	158110114910075	PPM.		
L4 and L5	17021032013		C4*	19A116114P10073	Ceramic: 180 pf ±10%, 100 VDCW; temp coef -3300 PPM. Added by REV A.	P1 and P2	19A115834P4
			L			L	L

DESCRIPTION		SYMBOL	
·	ŀ		L
Silicon, PNP.	-		1
Silicon, NPN.	-		
RESISTORS	-	C11	19
Composition: 10K ohms ±5%, 1/8 w.		C12	19
Composition: 3.3K ohms ±5%, 1/8 w.			
Composition: 150K ohms ±5%, 1/8 w.			l
Composition: 1.8K ohms ±5%, 1/8 w.	1		
Composition: 6.8K ohms ±5%, 1/8 w.  Composition: 1.8K ohms ±5%, 1/8 w.		Sl	19
Composition: 1K ohms ±5%, 1/8 w.			
Composition: 150K ohms ±5%, 1/8 w.			
Composition: 1.2K ohms ±5%, 1/8 w.			
JACKS AND RECEPTACLES		A50	19
Connector, female: 6 contacts.			
See Mechanical Parts RC2147 items 14, 16.		C50	54
See Mechanical Parts RC2147 items 14, 47, 49.		and C51	
See Mechanical Parts RC2147 items 51-53, 61.		C52	54
RELAYS		C53*	19
Sensitive: 95 ohms $\pm 10\%$ , 2 form C contacts, 5.5 to 9.0 VDC (over the temp range indicated); sim to		and C54*	1
C.P. Clare MF1401G01. Deleted by REV E.			l
		R50	31
Coil,		R51	31
			l
			ı
		250	
Contact, electrical: sim to AMP 2-332070-9.		R52 R53	31
Plug: 8 contacts.		1100	٦
			١.,
Resistor/Switch: variable, carbon film, 25K ohms			19
±20%, 1/8 w, (Includes S703), SPST, 3 amp at 125 VAC; sim to Mallory Type MZC.			
Variable, carbon film: 25K ohms ±10%, 1/8 w; sim to Mallory Type MZC.	H		19
SWITCHES			1
See Mechanical Parts RC2147, items 32-38.	$  \  $		4
See Mechanical Parts RC2147, items 39-46.	Н		1
(Part of R707).	$  \  $		
Cable. (Includes P704 & P705).	$  \  $		
		A5	4
ASSOCIATED ASSEMBLIES		and A6	-
	П		
FRONT COVER ASSEMBLY 19C317416G1 (STD)	$  \  $		l
19C317416G4 (HI POWER)	$\  \ $	1	1
LOUDSPEAKERS	$  \  $	2	1
Permanent magnet: 2.00 inch, 8 ohms ±15% voice coil imp, 500 Hz ±50 Hz resonant; sim to Oaktron		3	1
T6703.  Earlier than REV A:	$  \  $	4	N
Description 2 00 inch & ohms +10% voice		5	1
coil imp, 450 Hz ±112 Hz resonant; freq range 400 to 3000 Hz.		6 7	4 N
PLUGS		•	"
Contact, electrical: sim to AMP 2-332070-9.			
_			
	Ιĺ		

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
			8	19B232784G1
		HI/LOW SPLIT MODIFICATION KIT 19A127838G1 HI SPLIT	9	19B219953G3
		19A127838G2 LOW SPLIT	10	19D413531P2
				19B226502G2
C11	19A116114P2047	Ceramic: 33 pf ±5%, 100 VDCW; temp coef -80 PPM.	11	NP270290P2
C12	19A116114P2051	Ceramic: 43 pf ±5%, 100 VDCW; temp coef -80 PPM.		NP270290P3
		1	12	19D413542G11
		MULTI-FREQUENCY MODIFICATION KIT 19A127828G1	"	100415542011
		1	13	19B216858P1
		SWITCHES	14	19A127753P1
Sl	19A127824G1	Toggle: DPDT, 100 µa at 5 VDC, 5 amps at 29 VDC, 5 amps at 115 VAC; sim to Arrow-Hart and Hegeman TS-6.	15	19A134548P1
			16	19B216862P2
	1	COMPRESSOR KIT 19A127837G1	17	19A127779G6
			18	19B216875P1
A50	19C311907G2	Audio Compressor Board.	19	19A129649P1
			20	19C320383P2
C50	5491674P1	Tantalum: 1.0 μf +40 -20%, 10 VDCW; sim to	21	19A129652P1
and C51		Sprague Type 162D.	22	19C32O352P1
C52	5491674P36	Tantalum: 3.3 µf ±20%, 10 VDCW; sim to Sprague	23	19A129390P1
		Type 162D.	24	19C317050P1
C53* and	19A116192P2	Ceramic: 470 pf ±20%, 50 VDCW; sim to Erie 8111-050-w5R. Added by REV A.	25	19C317383P1
C54*		offi-odd work. Added by Abr A.	26	19A129723P1
		RESISTORS	27	19B219540P1
R50	3R151P103J	Composition: 10K ohms ±5%, 1/8 w.	28	19C320721P1
R51	3R151P101J	Composition: 100 ohms ±5%, 1/8 w.	29	19B216926P5
R52 R53	3R151P153J 3R151P433J 19B216897G1 19B216897G2 19B219953G3 19D413522G4	Composition: 15K ohms ±5%, 1/8 w.  Composition: 43K ohms ±5%, 1/8 w.  MISCELLANEOUS  Rear Cover Assembly. (See RC2147, items 58, 59).  Rear Cover Assembly. Clip type. (See RC2147, items 58, 60).  Antenna Assembly. (See RC2147, items 7, 19-22).  Battery, rechargeable. Nickel Cadmium.	30 31 32 33 34 35 36 37	19A115983P3 N509P606C N55P1006 19C328416G1 19C328407P1 19A137621P1 19A137620P1 N207P1C6
	19A127884G1	Fuse Kit.	38	19B209643P2
	4038381P4	Alianment tool. Fork tip.	39	19B216865P1
	19B219079G1	Alignment tool. Allen tip.	40	N647P5004C
			41	19B216864P1
	Ì	ASSOCIATED PARTS	11	19B216863P1
		NOTE: When reordering A5, A6 give GE Part Number	42	
		and exact crystal frequency. Crystal Freq = (0F)	43	N910P6C6
		Townstates Contillator	44	19A127754P1
A5 and	4EG27A10	Transmitter Oscillator.	45	19A127755P1
A6			46	19B216862P1
		MECHANICAL PARTS	47	N330P605F22
		(SEE RC2147)	48	N330P602F22
1	19A134425P1	Machine, screw, hex head: No. 2-56 x 3/16.	49	19A127760P1
2	19C317394P3	Gasket.	50	19A127762P1
3	19B204527P2	Diaphragm: No. 2 inch dia.	51	19B216891G1
4	N681P5002C6	Screw, phillips head: No. 2-56 x 1/8.	52	19D413467P1
5	19A127319P1	Nut: No. thd. size 1/4-32.	53	19A115794P3
6	4037064P18	Washer, non-metallic.	54	19B216847P1
7	N70P703C6	Set screw: No. 3-48 x 3/16.	55	19C311491P3
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SY	MBOL	GE PART NO.	DESCRIPTION
8		19B232784G1	Knob Assembly. (Includes items 65 & 67).
9		19B219953G3	Antenna assembly. (Includes items 7, 19-22).
10		19D413531P2	Grille. (STD).
		19B226502G2	Grille. (HI POWER).
11		NP270290P2	Nameplate. (GE monogram STD).
		NP270290P3	Nameplate. (GE monogram, HI POWER).
12		19D413542G11	Case assembly. (Includes items 14, 15, 18, 26, 49, 68, 69).
13		19B216858P1	Insert.
14		19A127753P1	Contact. (Part of J702 & J703).
15		19A134548P1	Insert, screw thread: No. 2-56; sim to IN-X 860256.
16		19B216862P2	Contact. (Part of J702).
17		19A127779G6	Antenna tube.
18		19B216875P1	Support.
19		19A129649P1	Antenna Cap. (Part of item 9).
20		19C32O383P2	Antenna rod. (Part of item 9).
21		19A129652P1	Nut, knurled: thd size 7/16-40. (Part of item 9
22		19C32O352P1	Bushing (Part of item 9).
23		19A129390P1	Disc. (Located inside item 24).
24		19C317050P1	Protective Cover.
25		19C317383P1	Dummy plug.
26		19A129723P1	Rivet.
27		19B219540P1	Support.
28		19C320721P1	Boot, moisture seal.
29		19B216926P5	Decorative cap.
30		19A115983P3	Seal, "O" ring: sim to Parker Seal 2-10.
31		N509P606C	Dowel pin: 1/16 x 3/8.
32		N55P1006	Machine screw, steel: No. 0-80 x 3/8. (Part of S701).

Button assembly. (Part of S701).

Collar. (Part of S701).

Plate. (Part of S701).

Spring. (Part of S701).

Hex nut. (Part of S701).

Switch, push. (Part of S701).

Spring contact. (Part of S702).

Retaining ring. (Part of S702).

Cap screw: 2-56 x 1/4. (Part of S702).

Eyelet, brass: 1/16 x 1/16. (Not Used).

Flat head screw: 2-56 x 5/16. (Part of J704).

Insulator (Part of \$702).

Contact (Part of S702).

Gasket (Part of S702).

Spring (Part of S702).

Contact (Part of S702).

Contact (Part of J703).

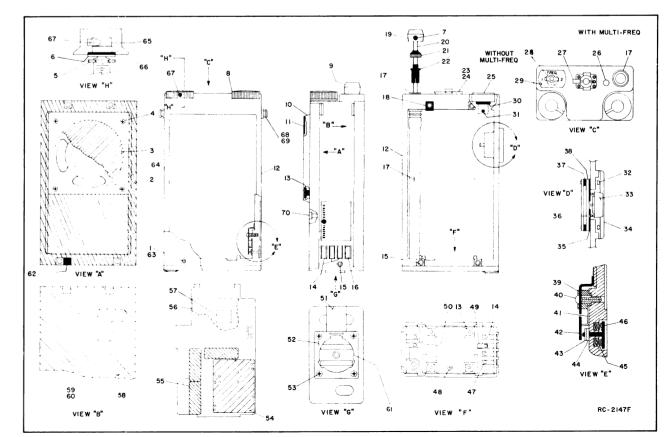
Fastener (Part of J704).

Insulator, pressure sensitive.

Eyelet, brass: 1/16 x 5/32.

Spring assembly. (Part of J704).

SYMBOL	GE PART NO.	DESCRIPTION
56	19B216912P1	Insulator. (Located between System and Receiver Boards).
57	19A116270P1	Tape, pressure sensitive.
58	19C317394P5	Gasket.
59	19B216897G1	Rear Cover Assembly (without clip).
60	19B216897G2	Rear Cover Assembly (with clip).
61	19A130586P1	Insulator.
62	19A130397P1	Strap.
63	N404P8P	Lockwasher, internal tooth: No. 2. (Not Used).
64	19A130993P1	Gasket.
65	19A137254P1	Insert, tapped.
66	4035630P1	Washer: teflon.
67	N70BP703C6	Set screw: No. 3-48 x 3/16.
68	19A116773P805	Tap screw, Phillips POZIDRIV®: No. 4-24 x 5/16.
69	19A127802P1	Rivet, shield.
70	N170P9004P2	Cap screw: No. 4-40 x 1/4.
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<sup>\*</sup>COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

#### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Case Assembly 19D413548G1

To remove antenna connection wire to Accessory Jack. Deleted White wire from J701-3 to antenna connector.

REV. A - Systems Board A701 (19D413552G1)

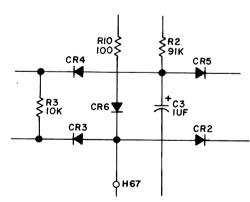
To improve symmetry, maximum deviation, power output and modulation limiting at temperature and voltage extremes. Changed Audio Module Al, Compensator Module A3 and Modulator Module A4. Replaced C6 with C19, and added C20.

REV. B - To increase mike sensitivity. Deleted MK1. Changed C5.

REV. C - To improve manufacture.
Added callouts for Holes H16, H64 and H67 thru H81.

REV. D - To improve FM hum and noise. Deleted CR3, CR4 and R3.

Schematic Diagram was:



REV. A - Compressor Kit 19A127837G1
To reduce audio distortion.
Added C53 and C54.

REV. B - Case Assembly 19D413548G1
To improve accessory jack J701. Added disc.

REV. C - To improve case assembly. Incorporated new design.

REV. D - To improve accessory jack J701. Changed J701.

REV. E - System Board A701 (19D413552G1)
To make compatible with more options.
Deleted XK1. Changed K1 and R1.

REV. E - Case Assembly 19D413548G1
To make compatible with more options.

REV. F - To improve case assembly design.

REV. G - To incorporate metal nuts for PTT switch mounting screws. Added nuts.

REV. F - System Board A701 (19D413552G1)

To improve PTT relay pick-up. Changed K1 and R1.

REV. G - To increase modulation level and improve frequency response. Changed C3, C5, R2, R5 and R6.

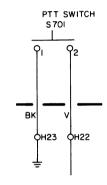
REV. H - To optimize audio frequency response. Changed C3 and C5.

REV. J - To incorporate a new 5.4 volt regulator. Changed A2 and added C21.

REV. H - Case Assembly 19D413548G1

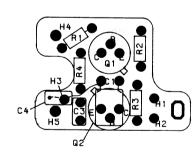
To improve reliability and design. Changed S701 and Knobs. Added A719.

Schematic Diagram was:

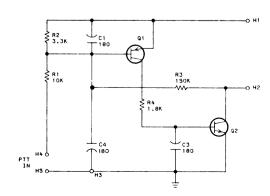


REV. J - To make compatible with GE-STAR Option. Changed A719.

Outline Diagram was:

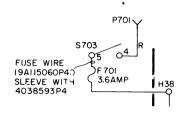


Schematic Diagram was:



REV. K - <u>System Board A701 (19D413552G1)</u>
To change fuse and make an integral part of system board.
Changed F701.

Schematic Diagram was:



REV. L - To improve modulation .
Added C22 and C23.

REV. M - To optimize transmit audio quality. Changed C3 and C4.

REV. A - PTT Switch 19B232586G1 To improve RF filtering Added C4.

REV. A - PTT Switch 19B23258662
To improve RF filtering.
Deleted C1. Changed R7.

REV. B - To improve RF filtering.
Added C5.

REV. C - To optimize component orientation. Re-layed out circuit baord making room for C2 used with GE-STAR option.

Outline Diagram was:

